Product data sheet

1. General description

The 74LV165-Q100 is an 8-bit serial or parallel-in/serial-out shift register. The device features a serial data input (DS), eight parallel data inputs (D0 to D7) and two complementary serial outputs (Q7 and $\overline{\text{Q7}}$). When the parallel load input ($\overline{\text{PL}}$) is LOW the data from D0 to D7 is loaded into the shift register asynchronously. When $\overline{\text{PL}}$ is HIGH data enters the register serially at DS. When the clock enable input ($\overline{\text{CE}}$) is LOW data is shifted on the LOW-to-HIGH transitions of the CP input. A HIGH on $\overline{\text{CE}}$ will disable the CP input. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess V_{CC} .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- · Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 1.0 V to 5.5 V
- · CMOS low power dissipation
- Direct interface with TTL levels (2.7 V to 3.6 V)
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Optimized for low voltage applications: 1.0 V to 3.6 V
- · Synchronous parallel-to-serial applications
- Synchronous serial input for easy expansion
- Complies with JEDEC standards:
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
 - JESD36 (4.5 V to 5.5 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

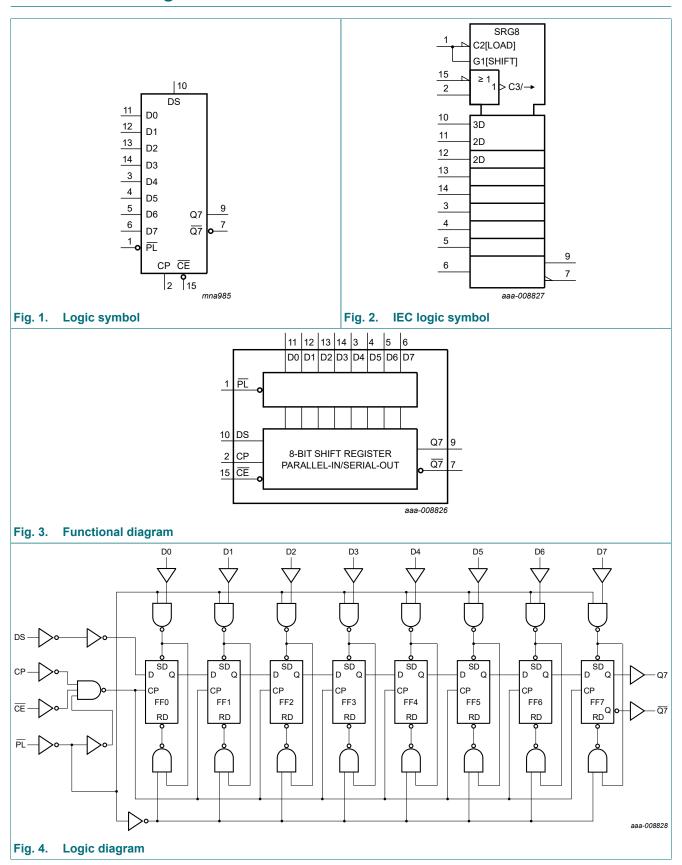
3. Ordering information

Table 1. Ordering information

Type number	Package	ackage					
	Temperature range	Name	Description	Version			
74LV165D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1			
74LV165PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1			

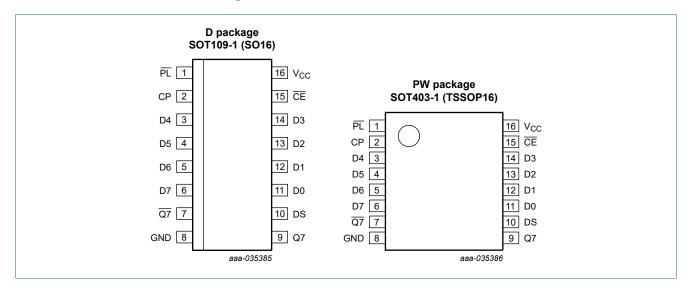


4. Functional diagram



5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
PL	1	parallel enable input (active LOW)
СР	2	clock input (LOW-to-HIGH edge-triggered)
Q7	7	complementary serial output from the last stage
GND	8	ground (0 V)
Q7	9	serial output from the last stage
DS	10	serial data input
D0, D1, D2, D3, D4, D5, D6, D7	11, 12, 13, 14, 3, 4, 5, 6	parallel data inputs
CE	15	clock enable input (active LOW)
V _{CC}	16	positive supply voltage

Product data sheet

6. Functional description

Table 3. Function table

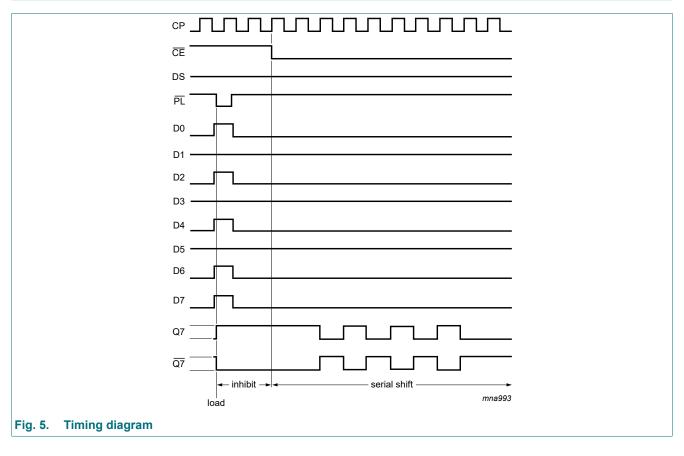
 $H = HIGH \ voltage \ level; \ h = HIGH \ voltage \ level \ one \ set-up \ time \ prior \ to \ the \ LOW-to-HIGH \ clock \ transition;$

L = LOW voltage level; I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

q = state of the referenced output one set-up time prior to the LOW-to-HIGH clock transition;

 $X = don't care; \uparrow = LOW-to-HIGH clock transition.$

Operating modes	Operating modes Inputs				Qn registe	rs	Output		
	PL	CE	СР	DS	D0 to D7	Q0	Q1 to Q6	Q7	Q7
parallel load	L	Х	Х	Х	L	L	L to L	L	Н
	L	Х	Х	X	Н	Н	H to H	Н	L
serial shift	Н	L	1	I	X	L	q0 to q5	q6	q 6
	Н	L	1	h	Х	Н	q0 to q5	q6	q 6
hold "do nothing"	Н	Н	Х	X	X	q0	q1 to q6	q7	q7



8-bit parallel-in/serial-out shift register

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V). [1]

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	20	mA
VI	input voltage		-0.5	+7	V
I _{OK}	output clamping current	V _O > V _{CC} or V _O < 0	-	±50	mA
I _O	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ [2]	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		1.0	3.3	5.5	V
VI	input voltage		0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 1.0 V to 2.0 V	0	-	500	ns/V
		V _{CC} = 2.0 V to 2.7 V	0	-	200	ns/V
		V _{CC} = 2.7 V to 3.6 V	0	-	100	ns/V
		$V_{CC} = 3.6 \text{ V to } 5.5 \text{ V}$	0	-	50	ns/V

5/16

^[2] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C.

8-bit parallel-in/serial-out shift register

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
V _{IH}	HIGH-level	V _{CC} = 1.2 V	0.9	-	-	0.9	-	V
	input voltage	V _{CC} = 2.3 V to 2.7 V	1.4	-	-	1.4	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
		V _{CC} = 4.5 V to 5.5 V	0.7 × V _{CC}	-	-	0.7 × V _{CC}	-	V
V _{IL}	LOW-level	V _{CC} = 1.2 V	-	-	0.3	-	0.3	V
	input voltage	V _{CC} = 2.3 V to 2.7 V	-	-	0.6	-	0.6	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
		V _{CC} = 4.5 V to 5.5 V	-	-	0.3 × V _{CC}	-	0.3 × V _{CC}	
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $I_O = -100 \mu A$						
	output voltage	V _{CC} = 1.2 V	-	1.2		-		
		V _{CC} = 2.0 V	1.8	2.0	-	1.8	-	V
		V _{CC} = 2.7 V	2.5	2.7	-	2.5	-	V
		V _{CC} = 3.0 V	2.8	3.0	-	2.8	-	V
		V _{CC} = 4.5 V	4.3	4.5	-	4.3	-	V
		standard outputs: V _I = V _{IH} or V _{IL}						
		V _{CC} = 3.0 V; I _O = -6 mA	2.40	2.82	-	2.20	-	V
		V _{CC} = 4.5 V; I _O = -12 mA	3.60	4.20	-	3.50	-	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $I_O = 100 \mu A$						
	output voltage	V _{CC} = 1.2 V	-	0	-	-	-	
		V _{CC} = 2.0 V	-	0	0.2	1.8	0.2	V
		V _{CC} = 2.7 V	-	0	0.2	2.5	0.2	V
		V _{CC} = 3.0 V	-	0	0.2	2.8	0.2	V
		V _{CC} = 4.5 V	-	0	0.2	4.3	0.2	V
		standard outputs: $V_I = V_{IH}$ or V_{IL}						
		V _{CC} = 3.0 V; I _O = 6 mA	-	0.25	0.40	-	0.50	V
		V _{CC} = 4.5 V; I _O = 12 mA	-	0.35	0.55	-	0.65	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1	-	±1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	20	-	160	μΑ
ΔI _{CC}	additional supply current	V _I = V _{CC} - 0.6 V; V _{CC} = 2.7 V to 3.6 V	-	-	500	-	850	μΑ
C _I	input capacitance		-	3.5	-	-	-	pF

^[1] Typical values are measured at T_{amb} = 25 °C.

8-bit parallel-in/serial-out shift register

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND (ground = 0 V); for test circuit, see Fig. 11.

Symbol	Parameter	Conditions	-4	0 °C to +85	s °C	-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
t _{pd}	propagation delay	CE, CP to Q7, Q7; [2] see Fig. 6 and Fig. 7						
		V _{CC} = 1.2 V	-	115	-	-	-	ns
		V _{CC} = 2.0 V	-	38	61	-	76	ns
		V _{CC} = 2.7 V	-	27	43	-	54	ns
		V _{CC} = 3.0 V to 3.6 V [3]	-	22	36	-	45	ns
		V _{CC} = 3.3 V; C _L = 15 pF	-	18	-	-	-	ns
		V _{CC} = 4.5 V to 5.5 V [4]	-	15	24	-	30	ns
		PL to Q7, Q7; see Fig. 7						
		V _{CC} = 1.2 V	-	110	-	-	-	ns
		V _{CC} = 2.0 V	-	35	56	-	70	ns
		V _{CC} = 2.7 V	-	24	39	-	49	ns
		V _{CC} = 3.0 V to 3.6 V [3]	-	20	33	-	41	ns
		$V_{CC} = 3.3 \text{ V}; C_L = 15 \text{ pF}$	-	18	-	-	-	ns
		V _{CC} = 4.5 V to 5.5 V [4]	-	14	22	-	27	ns
		D7 to Q7, Q7; see Fig. 8						
		V _{CC} = 1.2 V	-	90	-	-	-	ns
		V _{CC} = 2.0 V	-	28	45	-	56	ns
		V _{CC} = 2.7 V	-	20	32	-	40	ns
		V _{CC} = 3.0 V to 3.6 V [3]	-	17	27	-	33	ns
		$V_{CC} = 3.3 \text{ V}; C_L = 15 \text{ pF}$	-	14	-	-	-	ns
		V _{CC} = 4.5 V to 5.5 V [4]	-	11	18	-	22	ns
t _W	pulse width	CP input HIGH to LOW; see Fig. 6						
		V _{CC} = 2.0 V	34	10	-	41	-	ns
		V _{CC} = 2.7 V	25	8	-	30	-	ns
		V _{CC} = 3.0 V to 3.6 V [3]	20	7	-	24	-	ns
		V _{CC} = 4.5 V to 5.5 V [4]	15	5	-	18	-	ns
		PL input LOW; see Fig. 7						
		V _{CC} = 2.0 V	34	10	-	41	-	ns
		V _{CC} = 2.7 V	25	8	-	30	-	ns
		V _{CC} = 3.0 V to 3.6 V [3]	20	7	-	24	-	ns
		V _{CC} = 4.5 V to 5.5 V [4]	15	5	-	18	-	ns
t _{rec}	recovery time	PL to CP, CE; see Fig. 7						
		V _{CC} = 1.2 V	-	40	-	-	-	ns
		V _{CC} = 2.0 V	24	15	-	30	-	ns
		V _{CC} = 2.7 V	18	11	-	23	-	ns
		V _{CC} = 3.0 V to 3.6 V [3]	17	10	-	21	-	ns
		V _{CC} = 4.5 V to 5.5 V [4]	12	7	-	15	-	ns

8-bit parallel-in/serial-out shift register

Symbol	Parameter	Conditions		-40	°C to +85	s °C	-40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t _{su}	set-up time	DS to CP, CE; see Fig. 9							
		V _{CC} = 1.2 V		-	-8	-	-	-	ns
		V _{CC} = 2.0 V		22	-2	-	26	-	ns
		V _{CC} = 2.7 V		16	-1	-	19	-	ns
		V_{CC} = 3.0 V to 3.6 V	[3]	13	-1	-	15	-	ns
		V _{CC} = 4.5 V to 5.5 V	[4]	9	0	-	10	-	ns
		CE to CP, CP to CE; see Fig. 9							
		V _{CC} = 1.2 V		-	20	-	-	-	ns
		V _{CC} = 2.0 V		22	7	-	26	-	ns
		V _{CC} = 2.7 V		16	5	-	19	-	ns
		V_{CC} = 3.0 V to 3.6 V	[3]	13	4	-	15	-	ns
		V _{CC} = 4.5 V to 5.5 V	[4]	9	3	-	10	-	ns
		Dn to PL; see Fig. 10							
		V _{CC} = 1.2 V		-	25	-	-	-	ns
		V _{CC} = 2.0 V		22	8	-	26	-	ns
		V _{CC} = 2.7 V		16	6	-	19	-	ns
		V_{CC} = 3.0 V to 3.6 V	[3]	13	5	-	15	-	ns
		V _{CC} = 4.5 V to 5.5 V	[4]	9	4	-	10	-	ns
t _h	hold time	DS to CP, CE; Dn to PL; see Fig. 9 and Fig. 10							
		V _{CC} = 1.2 V		-	20	-	-	-	ns
		V _{CC} = 2.0 V		22	7	-	26	-	ns
		V _{CC} = 2.7 V		16	5	-	19	-	ns
		V_{CC} = 3.0 V to 3.6 V	[3]	13	4	-	15	-	ns
		V_{CC} = 4.5 V to 5.5 V	[4]	9	3	-	10	-	ns
		CE to CP, CP to CE; see Fig. 9							
		V _{CC} = 1.2 V		-	-30	-	-	-	ns
		V _{CC} = 2.0 V		5	-8	-	5	-	ns
		V _{CC} = 2.7 V		5	-6	-	5	-	ns
		V_{CC} = 3.0 V to 3.6 V	[3]	5	-5	-	5	-	ns
		V_{CC} = 4.5 V to 5.5 V	[4]	5	-4	-	5	-	ns
f _{max}	maximum	see Fig. 6							
	frequency	V _{CC} = 2.0 V		14	40	-	12	-	MHz
		V _{CC} = 2.7 V		19	60	-	16	-	MHz
		V _{CC} = 3.0 V to 3.6 V	[3]	24	65	-	20	-	MHz
		V _{CC} = 3.3 V; C _L = 15 pF		-	78	-	-	-	MHz
		V _{CC} = 4.5 V to 5.5 V	[4]	36	75	-	30	-	MHz

8-bit parallel-in/serial-out shift register

Symbol	Parameter	Conditions	-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	Min	Max	
C _{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC};$ [5] $V_{CC} = 3.3 \text{ V}$	-	35	-	-	-	pF

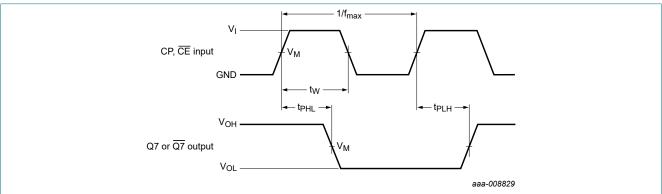
- Typical values are measured at T_{amb} = 25 °C. [1]
- [2] t_{pd} is the same as t_{PHL} and t_{PLH}.
- Typical values are measured at V_{CC} = 3.3 V. [3]
- Typical values are measured at $V_{CC} = 5.0 \text{ V}$.
- C_{PD} is used to determine the dynamic power dissipation $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o) (P_D \text{ in } \mu\text{W})$, where: f_i = input frequency in MHz;

f_o = output frequency in MHz;

 $\Sigma (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs; C_L = output load capacitance in pF;

V_{CC} = supply voltage in V.

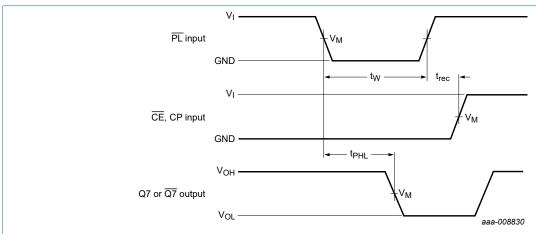
10.1. Waveforms and test circuit



Measurement points are given in Table 8.

The changing to output assumes that internal Q6 is opposite state from Q7.

Clock pulse (CP) and clock enable (CE) to output (Q7 or Q7) propagation delays, clock pulse width and Fig. 6. maximum clock frequency



Measurement points are given in Table 8.

The changing to output assumes that internal Q6 is opposite state from Q7.

Fig. 7. Parallel load (\overline{PL}) pulse width, parallel load to output (Q7 or $\overline{Q7}$) propagation delays, parallel load to clock (CP) and clock enable (CE) recovery time

8-bit parallel-in/serial-out shift register

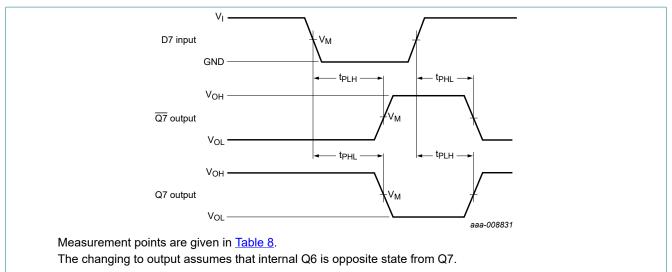
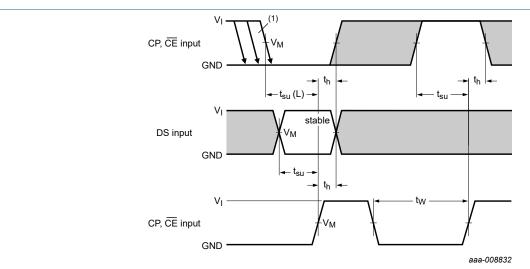


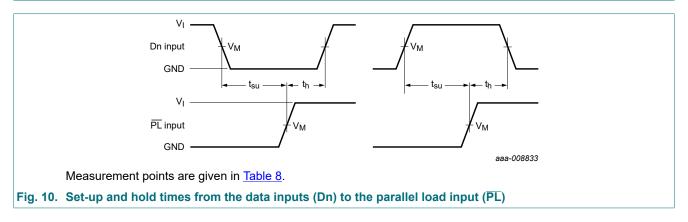
Fig. 8. Data input (Dn) to output (Q7 or $\overline{Q7}$) propagation delays when \overline{PL} is LOW



Measurement points are given in Table 8.

(1) CE may change only from HIGH-to-LOW while CP is LOW. The shaded areas indicate when the input is permitted to change for predictable output performance.

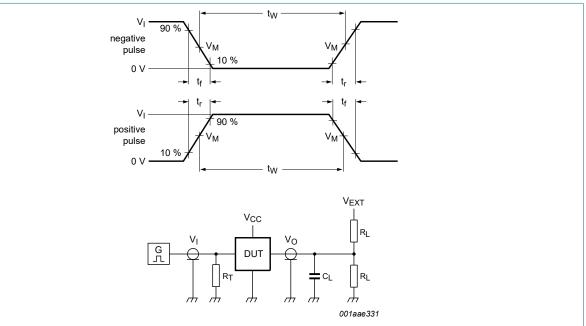
Fig. 9. Set-up and hold times



8-bit parallel-in/serial-out shift register

Table 8. Measurement points

Supply voltage	Input	Output
V _{CC}	V _M	V _M
< 2.7 V	0.5 × V _{CC}	0.5 × V _{CC}
2.7 V to 3.6 V	1.5 V	1.5 V
≥ 4.5 V	0.5 × V _{CC}	0.5 × V _{CC}



Test data is given in Table 9.

Definitions for test circuit:

R_L = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

 R_{T} = Termination resistance should be equal to output impedance Z_{o} of the pulse generator;

V_{EXT} = External voltage for measuring switching times.

Fig. 11. Test circuit for measuring switching times

Table 9. Test data

Supply voltage	Input		Load	V _{EXT}	
	V _I	t _r , t _f	C _L	R _L	t _{PHL} , t _{PLH}
< 2.7 V	V _{CC}	2.5 ns	50 pF	1 kΩ	open
2.7 V to 3.6 V	2.7 V	2.5 ns	50 pF, 15 pF	1 kΩ	open
≥ 4.5 V	V _{CC}	2.5 ns	50 pF	1 kΩ	open

11. Package outline

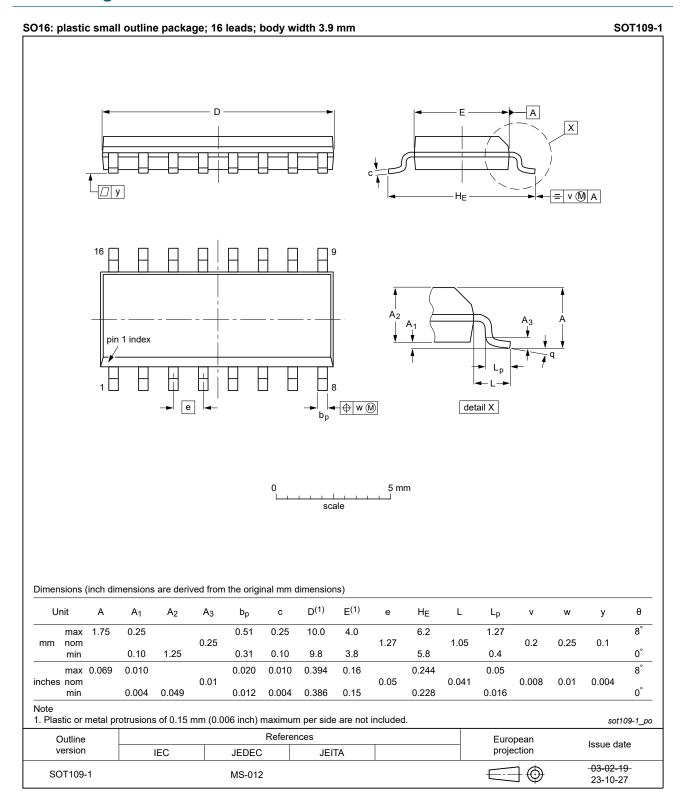


Fig. 12. Package outline SOT109-1 (SO16)

8-bit parallel-in/serial-out shift register

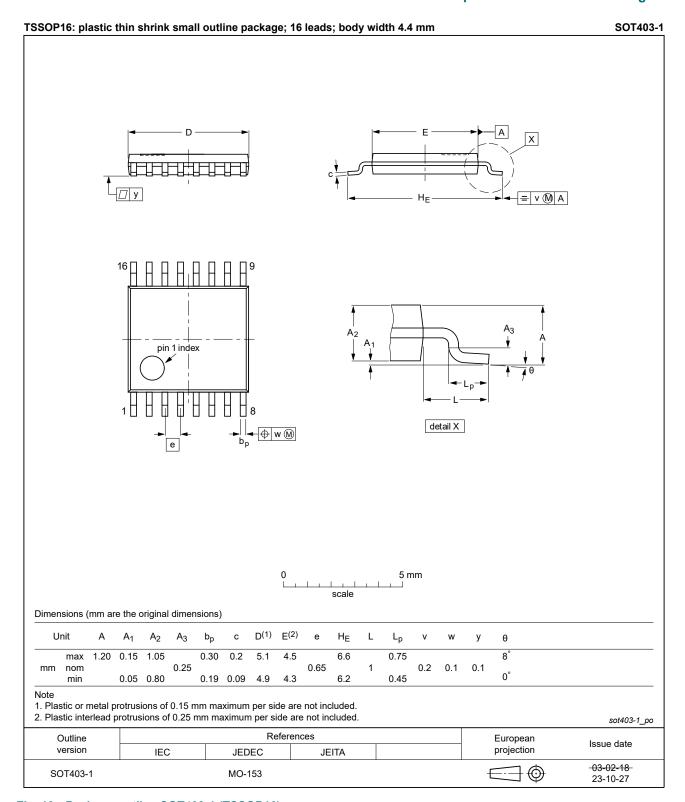


Fig. 13. Package outline SOT403-1 (TSSOP16)

8-bit parallel-in/serial-out shift register

12. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
TTL	Transistor-Transistor Logic

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74LV165_Q100 v.5	20240131	Product data sheet	-	74LV165_Q100 v.4		
Modifications:	• <u>Fig. 12, Fig.</u>	 <u>Section 2</u>: ESD specification updated according to the latest JEDEC standard. <u>Fig. 12</u>, <u>Fig. 13</u>: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and MO-153 				
74LV165_Q100 v.4	20220905	Product data sheet	-	74LV165_Q100 v.3		
Modifications:	<u>Section 8</u> : Maximum value for T _{amb} ambient temperature corrected to +125 °C.					
74LV165_Q100 v.3	20210921	Product data sheet	-	74LV165_Q100 v.2		
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Section 1 and Section 2 updated. Section 7: Derating values for P_{tot} total power dissipation updated. 					
74LV165_Q100 v.2	20140224	Product data sheet	-	74LV165_Q100 v.1		
Modifications:	Typo corrected in <u>Table 2</u>					
74LV165_Q100 v.1	20131111	Product data sheet	-	-		

8-bit parallel-in/serial-out shift register

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- 2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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8-bit parallel-in/serial-out shift register

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